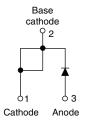


VS-20ETS16PbF, VS-20ETS16-M3

Vishay Semiconductors

High Voltage, Input Rectifier Diode, 20 A





| PRODUCT SUMMARY | | | | |
|----------------------------------|------------|--|--|--|
| Package | TO-220AC | | | |
| I _{F(AV)} | 20 A | | | |
| V_{R} | 1600 V | | | |
| V _F at I _F | 1.1 V | | | |
| I _{FSM} | 300 A | | | |
| T _J max. | 150 °C | | | |
| Diode variation | Single die | | | |

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





COMPLIANT HALOGEN FREE

APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

| OUTPUT CURRENT IN TYPICAL APPLICATIONS | | | | | | |
|---|------|----|---|--|--|--|
| APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS | | | | | | |
| Capacitive input filter T _A = 55 °C, T _J = 125 °C common heatsink of 1 °C/W | 16.3 | 21 | А | | | |

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|-----------------------------------|------------------------------|-------------|----|--|--|--|
| SYMBOL CHARACTERISTICS VALUES UNI | | | | | | |
| I _{F(AV)} | Sinusoidal waveform | 20 | Α | | | |
| V _{RRM} | | 1600 | V | | | |
| I _{FSM} | | 300 | Α | | | |
| V _F | 10 A, T _J = 25 °C | 1.0 | V | | | |
| T _J | | -40 to +150 | °C | | | |

| VOLTAGE RATINGS | | | | | | |
|-----------------|---|--|-------------------------------------|--|--|--|
| PART NUMBER | V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} AT 150 °C mA | | | |
| VS-20ETS16PbF | 1600 | 1700 | 4 | | | |
| VS-20ETS16-M3 | 1600 | 1700 | ı | | | |



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| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--------------------------------------|--------------------|---|------|------------------|--|--|
| PARAMETER | VALUES | UNITS | | | | |
| Maximum average forward current | I _{F(AV)} | T _C = 105 °C, 180° conduction half sine wave | 20 | | | |
| Maximum peak one cycle | | 10 ms sine pulse, rated V _{RRM} applied | 250 | Α | | |
| non-repetitive surge current | I _{FSM} | 10 ms sine pulse, no voltage reapplied | 300 | | | |
| Maximum I ² t for fusing | l ² t | 10 ms sine pulse, rated V _{RRM} applied | 316 | A ² s | | |
| Waximum i-t for fusing | 1-1 | 10 ms sine pulse, no voltage reapplied 442 | | A-S | | |
| Maximum I ² √t for fusing | I²√t | t = 0.1 ms to 10 ms, no voltage reapplied | 4420 | A²√s | | |

| ELECTRICAL SPECIFICATIONS | | | | | | |
|--|--------------------|------------------------------|---|------|----|--|
| PARAMETER SYMBOL TEST CONDITIONS VALUES UNIT | | | | | | |
| Maximum forward voltage drop | V _{FM} | 20 A, T _J = 25 °C | | 1.1 | V | |
| Forward slope resistance | r _t | T 450.00 | | 10.4 | mΩ | |
| Threshold voltage | V _{F(TO)} | T _J = 150 °C | 0.85 | V | | |
| Maximum roveres leakage ourrent | | T _J = 25 °C | | 0.1 | m۸ | |
| Maximum reverse leakage current | I _{RM} | T _J = 150 °C | V _R = Rated V _{RRM} | 1.0 | mA | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|---------|-----------------------------------|---------------------------------------|-------------|-------------|--|
| PARAMETER | | SYMBOL | SYMBOL TEST CONDITIONS | | UNITS | |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | -40 to +150 | °C | |
| Maximum thermal resistance, junction to case | | R_{thJC} | DC operation 1.3 | | - °C/W | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth, and greased | 0.5 | O/ W | |
| A construction with | | | | 2 | g | |
| Approximate weight | | | | 0.07 | OZ. | |
| Mounting torque | minimum | | | 6 (5) | kgf · cm | |
| wounting torque | maximum | | | 12 (10) | (lbf·in) | |
| Marking device Case style TO-220AC 20ETS | | ΓS16 | | | | |

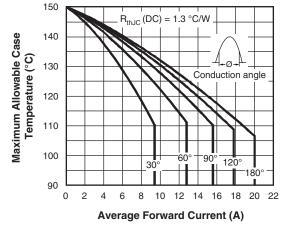


Fig. 1 - Current Rating Characteristics

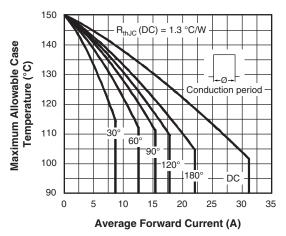


Fig. 2 - Current Rating Characteristics



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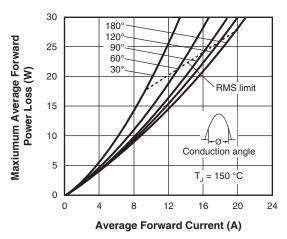


Fig. 3 - Forward Power Loss Characteristics

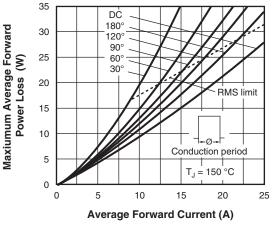


Fig. 4 - Forward Power Loss Characteristics

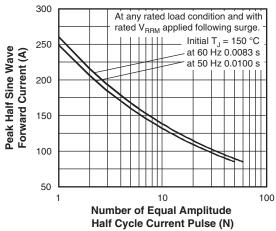


Fig. 5 - Maximum Non-Repetitive Surge Current

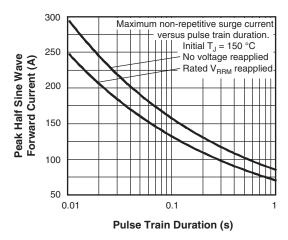


Fig. 6 - Maximum Non-Repetitive Surge Current

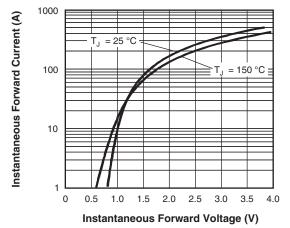


Fig. 7 - Forward Voltage Drop Characteristics

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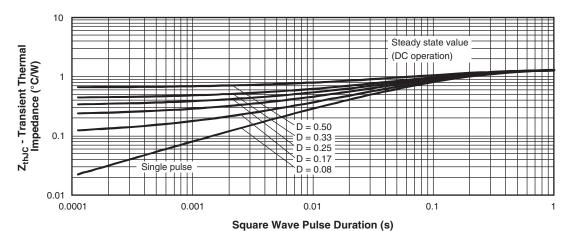
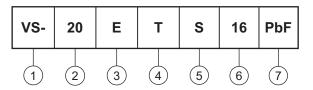


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (20 = 20 A)
- 3 Circuit configuration:

E = TO-220AC

4 - Package:

T = TO-220

5 - Type of silicon:

S = standard recovery rectifier

6 - Voltage rating (16 = 1600 V)

7 - Environmental digit:

PbF = lead (Pb)-free and RoHS-compliant

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-40ETS08PbF | 25 | 500 | Antistatic plastic tubes | | | | |
| VS-40ETS08-M3 | 25 | 500 | Antistatic plastic tubes | | | | |
| VS-40ETS12PbF | 25 | 500 | Antistatic plastic tubes | | | | |
| VS-40ETS12-M3 | 25 | 500 | Antistatic plastic tubes | | | | |

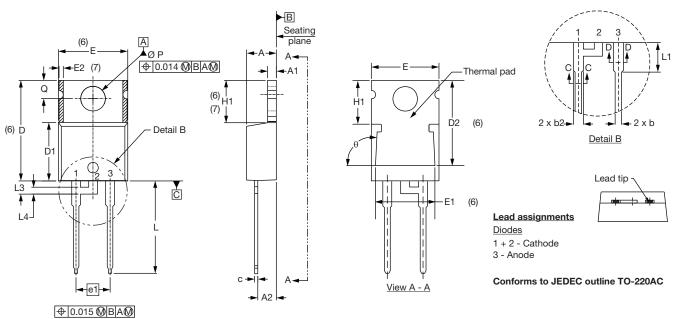
| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|-----------------------|--------------------------|--|--|--|
| Dimensions | | www.vishay.com/doc?95253 | | | |
| Doub wood in a information | TO-220AC modified PbF | www.vishay.com/doc?95255 | | | |
| Part marking information | TO-220AC modified -M3 | www.vishay.com/doc?95442 | | | |



Vishay Semiconductors

TO-220AC

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIM | IETERS | INCHES | | NOTES |
|----------|--------|--------|--------|-------|-------|
| STIVIBUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.25 | 4.65 | 0.167 | 0.183 | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | |
| A2 | 2.56 | 2.92 | 0.101 | 0.115 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.36 | 0.61 | 0.014 | 0.024 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 |
| D | 14.85 | 15.25 | 0.585 | 0.600 | 3 |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | |
| D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 |
| Е | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |

| SYMBOL | MILLIM | IETERS | INCHES | | NOTES |
|----------|------------|--------|--------|-------|-------|
| STINIBUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| E2 | - | 0.76 | - | 0.030 | 7 |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6, 7 |
| L | 13.52 | 14.02 | 0.532 | 0.552 | |
| L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| L3 | 1.78 | 2.13 | 0.070 | 0.084 | |
| L4 | 0.76 | 1.27 | 0.030 | 0.050 | 2 |
| ØΡ | 3.54 | 3.73 | 0.139 | 0.147 | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| θ | 90° to 93° | | 90° t | o 93° | |
| | | | | | |

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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